# RELAY DRIVE PROTECTION

## INTRODUCTION

A fast switch-off in an inductive circuit causes overvoltages and electromagnetic interferences that can damage peripheral elements. When a relay drive circuit is not protected, it is frequent to find some contacts destroyed by the arc due to the overvoltage or failed transistors after initial use. Various solutions exist which limit the voltage at the terminals of the switching circuit in order to prevent any damage.
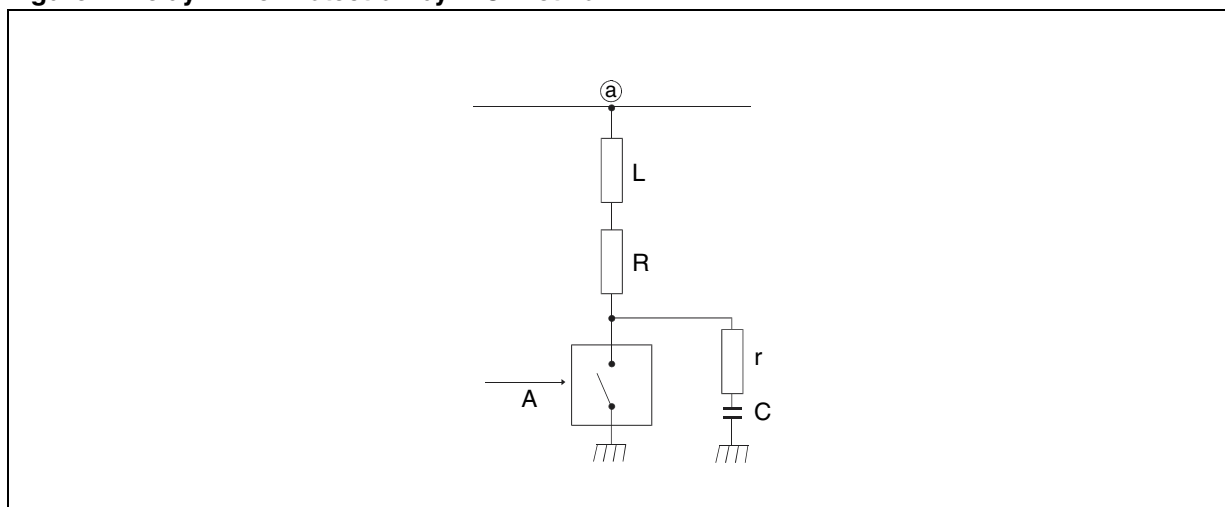
There follow some examples.

## PASSIVE COMPONENTS

Resistive network, capacitor (see circuit a, Figure 1).

This is an efficient solution in many applications but generates current peaks that can be inconvenient at switch-on.

**Figure 1. Relay Drive Protection by R.C. Network**



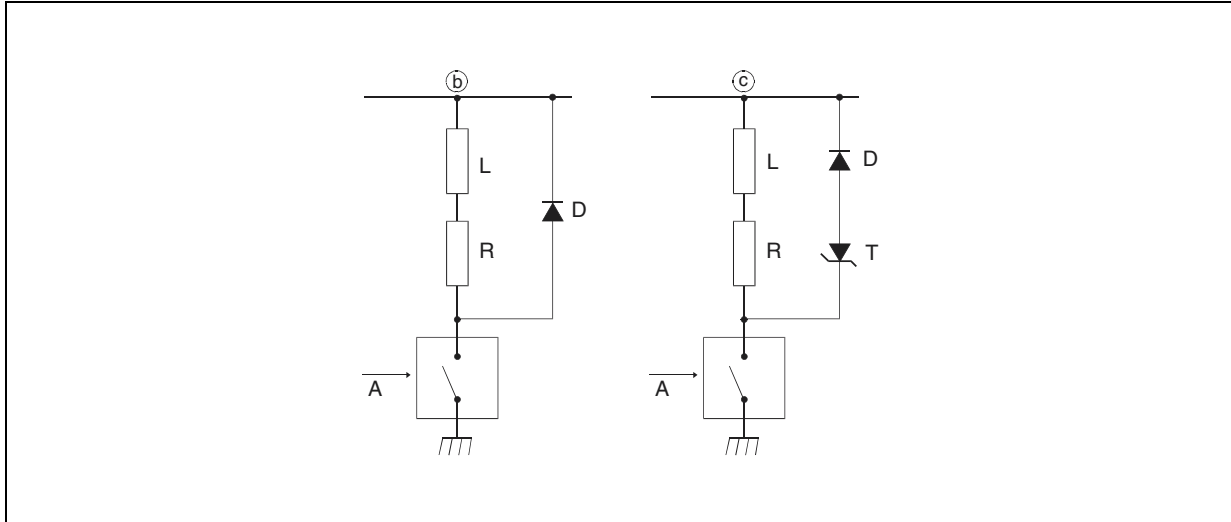## ELECTRONIC COMPONENTS

### Fast Diodes And Transil

Standard protection which puts a diode in antiparallel with the inductive load (see circuit b, Figure 2) offers many advantages: negligible overvoltage at switch on (forward voltage of the diode) reduced space, low price, good reliability and negligible permanent losses.

Unfortunately the current through the inductor does not stop immediately at switch-off; instead it decays with a time constant L/R. This is a disadvantage in some applications, for example a relay coil driver. The relay contacts will remain closed for some time after the switch is opened due to the current stored in the relay coil. It would be desirable to speed up the current decay rate while retaining the advantages of recovery diode protection.

A solution is shown in Figure 2, circuit c, in which a Transil diode is put in series with the recovery device. A much higher voltage is developed across the diode-Transil combination than across a single diode, thus accelerating the current decay.

**Figure 2. Relay Drive Protection**



Note: (b) Recovery Diode.
(c) Diode and Transil.

**Transil**

The Transil is an avalanche diode specially designed to clamp overvoltages and dissipate power in impulsive mode. It also offers the possibility of considerable average power absorption. It is available in different cases covering a wide range of voltages (5 to 600V).

Moreover, all the necessary data to calculate power parameters and to carry out temperature evaluation (Zth, Rth, etc...) can be found in technical notes. So the Transil is perfectly suited to this application.

In the case of a steady state power supply we can consider three hypotheses:

**Circuit d (Figure 3).** This is an economic solution which requires a unidirectional Transil only, but the current released by the inductance goes through the power supply and may affect the ground points.
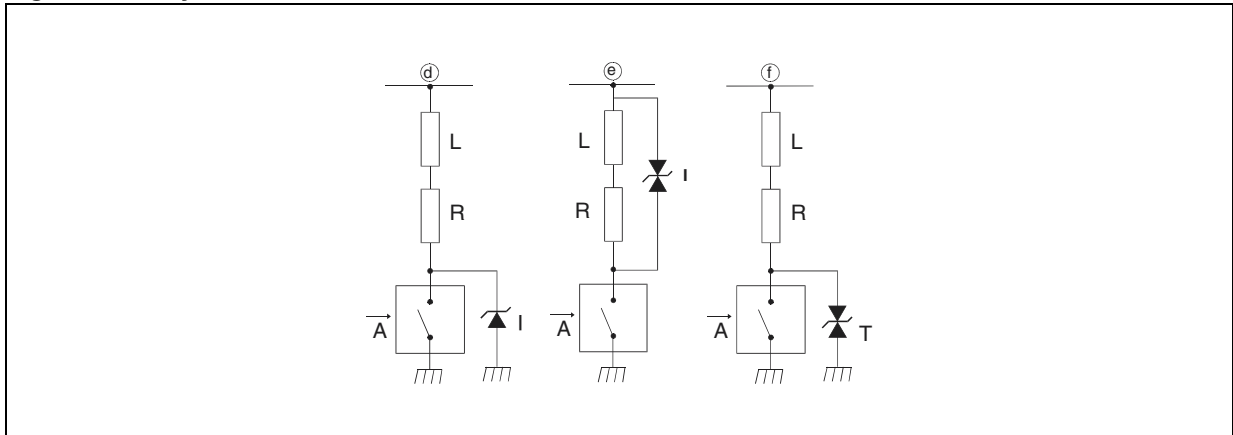
**Circuit c (Figure 2) and circuit e (Figure 3).** The inductive discharge current only goes through the LRD loop, thus is does not create disturbances in the ground points. This is a more expensive solution since two diodes or one bidirectional Transil are necessary. In the case of an alternating sinusoidal supply for low power, circuits e and f (Figure 3) are well suited to limit inductive overvoltages.

**Comparison of the Current Decay Time in the Inductive Load Between the Recovery Diode and the Transil Diode Schematics (see Figure 4)**

The ratio $t_2/t_1$ represents the reduction in current decay time when a Transil is used.

$$t_2/t_1 = \frac{1}{1 + 1,4 \cdot V_{CL}/V_{CC}}$$

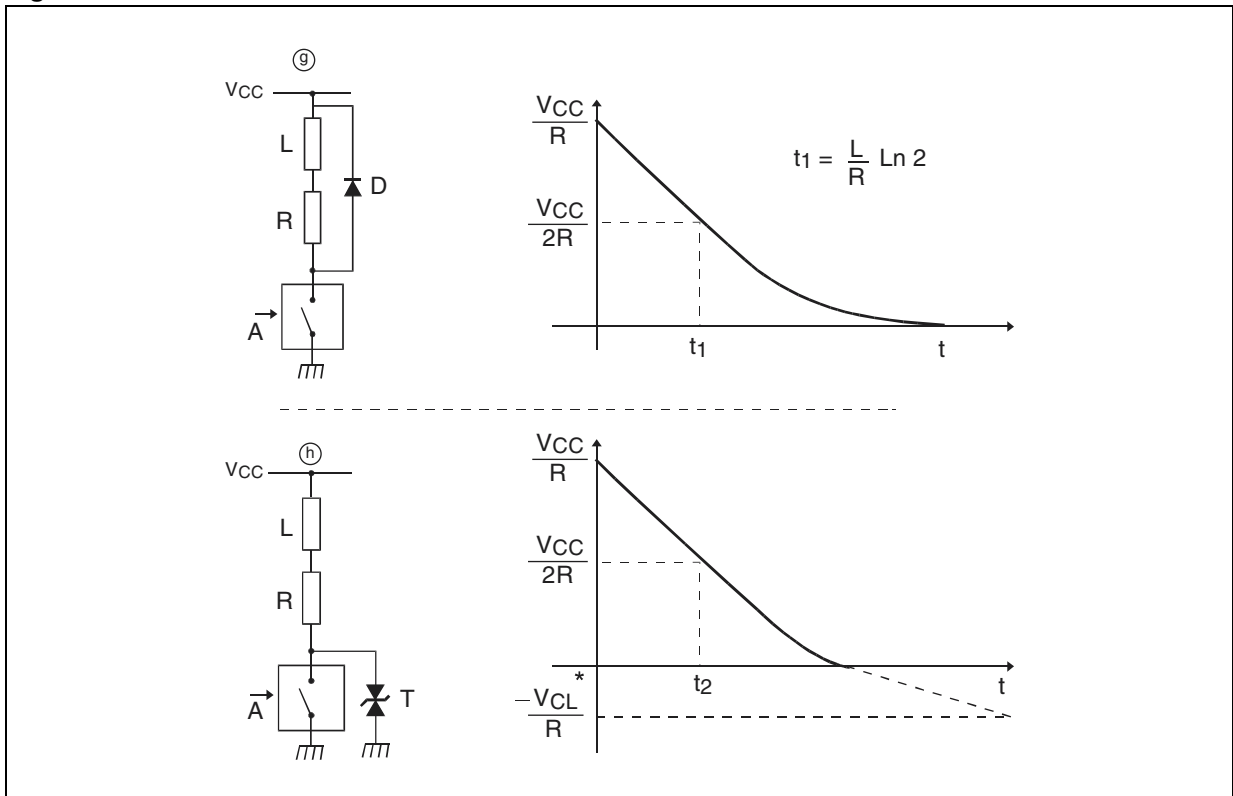**Figure 3. Relay Drive Protection**



Note: (d) Unidirectional Transil.
   (e) Bidirectional Transil.
   (f) Bidirectional Transil.

$V_{CL}$ is the voltage (measured) at the terminals of the Transil when the load current goes through it.

If we take $V_{CL} = V_{CC}$, we limit the overvoltage to a reasonable value and thus period $t_2$ represents only 0.4 x $t_1$. A correct choice of $V_{CL}$ will reduce $t_2$ to very low values and reach the mechanical limit given by the relay.

**Figure 4. Current in the inductance at switch off**



Note: (g) Recovery diode circuit: current slowly decreases to 0.
   (h) Transil circuit: current decreases rapidly (asymptote = $-V_{CL}^* / R$).

**CONCLUSION**

The Transil is a must in relay drive circuits. It guarantees a reliable and efficient protection while reducing the delay between the coil drive turn-off and the contact release.

**EXAMPLE OF APPLICATION: CALCULATION AND CHOICE OF A TRANSIL**

We wish to protect the transistor in Figure 5 by a Transil whose clamping voltage must not under any circumstances exceed $V_{CL}$ = 85V The clamping voltage is given by:

$$V_{CL} = V_{BR} + Rd\ IC$$

In the case of repetitive overload, the current is small enough such that the Rd Ic term can be neglected. Thus $V_{CL}$ approximates to:

$$V_{CL} = V_{BR}$$

The calculation is therefore simplified, and the Transil can be selected according to its thermal resistance.

**Mean Power Determination: $P_{AV}$**

A rough value can be obtained by assuming that all the energy contained in the inductance is absorbed by the Transil.

This is true when $V_{BR} \gg V_{CC}$.

$$P_{AV} = \frac{1}{2} \cdot LI^2 \cdot f = \frac{1}{2} \cdot 035 \cdot \left(\frac{12 + 24}{45}\right)^2 \cdot 50 = 09\,W$$

**Stand Off Voltage Selection**

The supply voltage varies between 9.6V and 14.4V.

The stand off voltage of the diode $V_{RM}$ will be

therefore be greater than or equal to 14.4V.

**$V_{CL}$ Determination**

From the data sheets we can see that for a low

current, $V_{CL} = V_{BR}$.

**$T_j$ Calculation**

$$T_j = T_{amb} + P_{AV}\ x\ R_{th} = 50 + 90 = 140°C < Tj\ max\ (150°C)$$

This value is consistent with the characteristics of the BZW04- 61B Transil (F 126 case) but the safety margin is somewhat low, so a device from the 1500 W series is preferable as a first choice.

$\{$ 1.5 KE 75CP (CB– 429 case): $V_{BR}\ max$ = 82.5V, $R_{th}$ = 75°C/W, $V_{RM}$ = 64.1V > 14.4V

$$T_j = 50 + 68 = 118°C \quad T_j\ max = 175°C$$

**Temperature Correction**

Voltage at 118°C is:

$$V_{CL}\ (118°C) = V_{CL}\ (25°C)\ [1 + \alpha T\ (118 - 25)] = [1 + 10.5\ x\ 10\text{-}4\ (93)]\ 82.5 = 90.5V$$
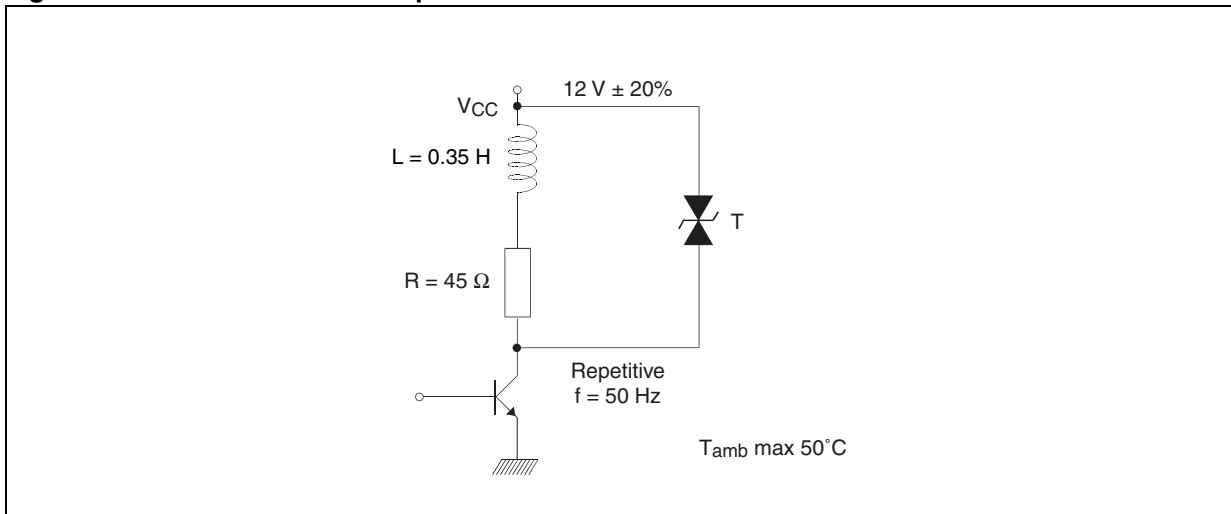
This value is too high.

**Definitive Choice**

$$1.5\ KE\ 68CP:\ V_{BR}\ max = 74.8V,\ V_{RM} = 58.1V > 14.4V$$

$$V_{CL}\ (118°C) = 1.098\ x\ 74.8 = 82.5V$$

$\Longrightarrow$ 1.5 KE 68CP is suitable.

**Figure 5. Schematic of the Example**

**REVISION HISTORY**

**Table 1. Revision History**

| Date | Revision | Description of Changes |
|:---:|:---:|---|
| March-1993 | 1 | First Issue |
| 16-Apr-2004 | 2 | Stylesheet update. No content change. |

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